

**SUPER FAST
GLASS PASSIVATED RECTIFIERS**

REVERSE VOLTAGE - 100 to 600 Volts
FORWARD CURRENT - 12 Amperes

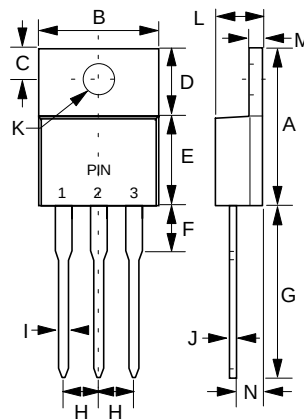
FEATURES

- Glass passivated chip
- Superfast switching time for high efficiency
- Low forward voltage drop and high current capability
- Low reverse leakage current
- High surge capacity
- Plastic package has UL flammability classification 94V-0

MECHANICAL DATA

- Case : TO-220AB molded plastic
- Polarity : As marked on the body
- Weight : 0.08 ounces, 2.24 grams
- Mounting position : Any

TO-220AB



TO-220AB		
DIM.	MIN.	MAX.
A	14.22	15.88
B	9.65	10.67
C	2.54	3.43
D	5.84	6.86
E	8.26	9.28
F	-	6.35
G	12.70	14.73
H	2.29	2.79
I	0.51	1.14
J	0.30	0.64
K	3.53 Ø	4.09 Ø
L	3.56	4.83
M	1.14	1.40
N	2.03	2.92

All Dimensions in millimeter

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	STPR 1210CT	STPR 1220CT	STPR 1230CT	STPR 1240CT	STPR 1250CT	STPR 1260CT	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	100	200	300	400	500	600	V
Maximum RMS Voltage	V _{RMS}	70	140	210	280	350	420	V
Maximum DC Blocking Voltage	V _{DC}	100	200	300	400	500	600	V
Maximum Average Forward Rectified Current @T _C =120°C	I(AV)	12						A
Non Repetitive Peak Forward Surge Current Per Diode Sinusoidal (JEDEC Method) T _P =8.3ms	I _{FSM}	60						A
Maximum forward Voltage IF=6A@T _J =25°C Pulse Width =300us IF=6A@T _J =125°C Duty cycle IF=12A@T _J =25°C IF=12A@T _J =125°C	V _F	1.1 1.0 1.25 1.20	1.3 1.2 1.5 1.4		1.5 1.4 1.7 1.6		V	
Maximum DC Reverse Current at Rated DC Blocking Voltage @T _J =25°C @T _J =100°C	I _R	10 250						uA
Typical Junction Capacitance per element (Note 1)	C _J	80						pF
Maximum Reverse Recovery Time (Note 2)	T _{RR}	30		35		50		ns
Typical Thermal Resistance	R _{θJC}	3.0						°C/W
Operating and Storage Temperature Range	T _J ,T _{STG}	-55 to +150						°C

NOTES : 1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
2.Reverse Recovery Test Conditions: $I_F=0.5A, I_R=1.0A, I_{RR}=0.25A$.

REV.0, Dec-2003, KTG11

FIG.1 - FORWARD CURRENT DERATING CURVE

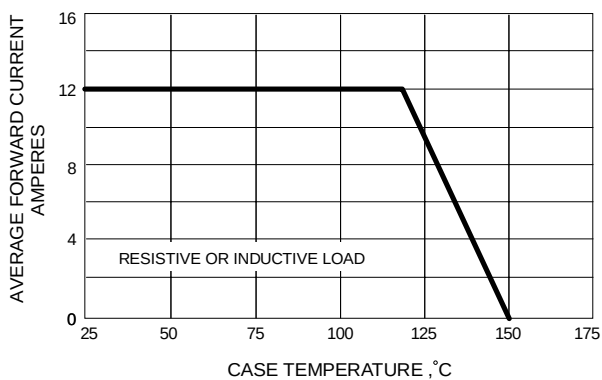


FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

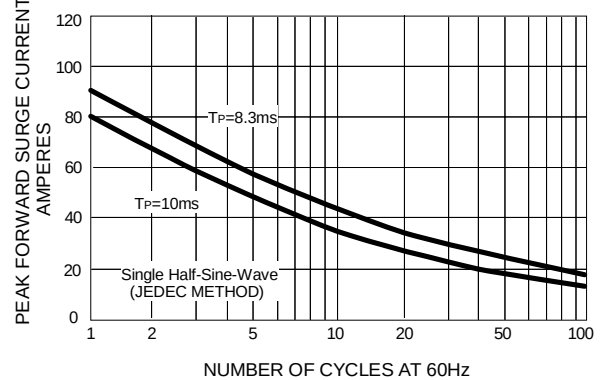


FIG.3 - TYPICAL REVERSE CHARACTERISTICS

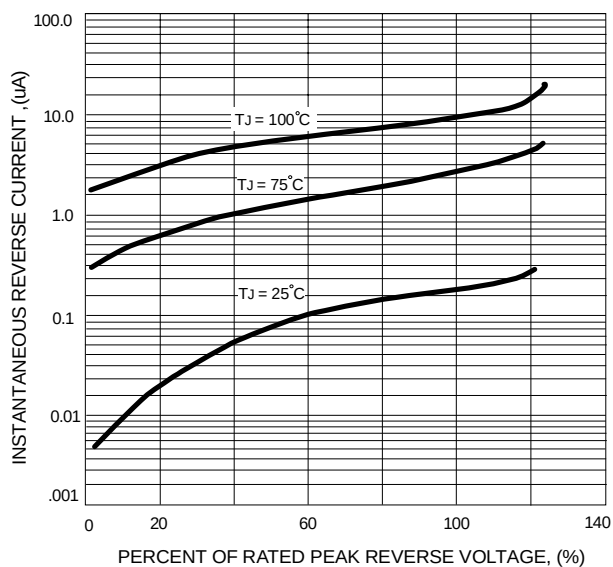


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

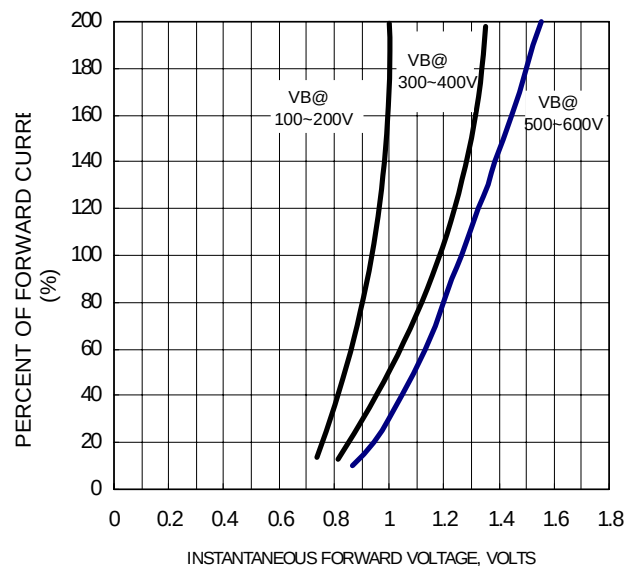


FIG.5 - TYPICAL JUNCTION CAPACITANCE

